

**MMBT2222A**

SMALL SIGNAL NPN TRANSISTOR

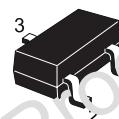
PRELIMINARY DATA

| Type | Marking |
|-----------|---------|
| MMBT2222A | M22 |

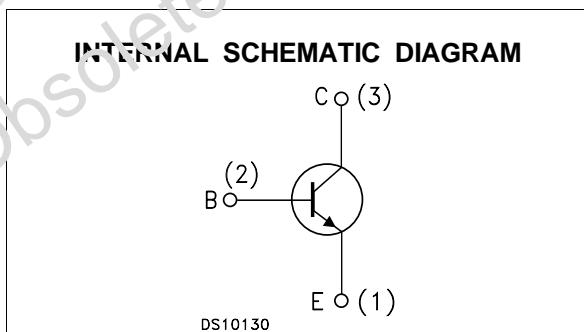
- SILICON EPITAXIAL PLANAR NPN TRANSISTOR
- MINIATURE SOT-23 PLASTIC PACKAGE FOR SURFACE MOUNTING CIRCUITS
- TAPE & REEL PACKING
- THE PNP COMPLEMENTARY TYPE IS MMBT2907A

APPLICATIONS

- WELL SUITABLE FOR PORTABLE EQUIPMENT
- SMALL LOAD SWITCH TRANSISTOR WITH HIGH GAIN AND LOW SATURATION VOLTAGE



SOT-23



ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|------------------|--|------------|------------------|
| V_{CBO} | Collector-Emitter Voltage ($I_E = 0$) | 75 | V |
| V_{CEO} | Collector-Emitter Voltage ($I_B = 0$) | 40 | V |
| V_{EBO} | Emitter-Base Voltage ($I_C = 0$) | 6 | V |
| I_C | Collector Current | 0.6 | A |
| I_{CM} | Collector Peak Current ($t_p < 5 \text{ ms}$) | 0.8 | A |
| P_{tot} | Total Dissipation at $T_{\text{amb}} = 25^\circ\text{C}$ | 350 | mW |
| T_{stg} | Storage Temperature | -65 to 150 | $^\circ\text{C}$ |
| T_j | Max. Operating Junction Temperature | 150 | $^\circ\text{C}$ |

MMBT2222A

THERMAL DATA

| | | | | |
|---|-------------------------------------|-----|-------|----------------------|
| $R_{thj\text{-amb}}$ • | Thermal Resistance Junction-Ambient | Max | 357.1 | $^{\circ}\text{C/W}$ |
| • Device mounted on a PCB area of 1 cm ² . | | | | |

ELECTRICAL CHARACTERISTICS ($T_{case} = 25^{\circ}\text{C}$ unless otherwise specified)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|-----------------|--|--|-----------------------------------|------|------------|--------------------------------------|
| I_{CEX} | Collector Cut-off Current ($V_{BE} = -3\text{ V}$) | $V_{CE} = 60\text{ V}$ | | | 10 | nA |
| I_{BEX} | Base Cut-off Current ($V_{BE} = -3\text{ V}$) | $V_{CE} = 60\text{ V}$ | | | 20 | nA |
| I_{CBO} | Collector Cut-off Current ($I_E = 0$) | $V_{CB} = 75\text{ V}$ $V_{CB} = 75\text{ V}$ $T_j = 150^{\circ}\text{C}$ | | | 10 10 | μA |
| I_{EBO} | Emitter Cut-off Current ($I_C = 0$) | $V_{EB} = 3\text{ V}$ | | | 15 | nA |
| $V_{(BR)CEO}^*$ | Collector-Emitter Breakdown Voltage ($I_B = 0$) | $I_C = 10\text{ mA}$ | 40 | | | V |
| $V_{(BR)CBO}$ | Collector-Base Breakdown Voltage ($I_E = 0$) | $I_C = 10\text{ }\mu\text{A}$ | 75 | | | V |
| $V_{(BR)EBO}$ | Emitter-Base Breakdown Voltage ($I_C = 0$) | $I_E = 10\text{ }\mu\text{A}$ | 6 | | | V |
| $V_{CE(sat)}^*$ | Collector-Emitter Saturation Voltage | $I_C = 150\text{ mA}$ $I_B = 15\text{ mA}$ $I_C = 500\text{ mA}$ $I_B = 50\text{ mA}$ | | | 0.3 1 | V |
| $V_{BE(sat)}^*$ | Collector-Base Saturation Voltage | $I_C = 150\text{ nA}$ $I_B = 15\text{ mA}$ $I_C = 500\text{ mA}$ $I_B = 50\text{ mA}$ | 0.6 | | 1.2 2 | V |
| h_{FE}^* | DC Current Gain | $I_C = 0.1\text{ mA}$ $V_{CE} = 10\text{ V}$ $I_C = 1\text{ mA}$ $V_{CE} = 10\text{ V}$ $I_C = 10\text{ mA}$ $V_{CE} = 10\text{ V}$ $I_C = 150\text{ mA}$ $V_{CE} = 10\text{ V}$ $I_C = 150\text{ mA}$ $V_{CE} = 1\text{ V}$ $I_C = 500\text{ mA}$ $V_{CE} = 10\text{ V}$ | 35 50 75 100 50 40 | | 300 | |
| f_T | Transition Frequency | $I_C = 20\text{ mA}$ $V_{CE} = 20\text{V}$ $f = 100\text{MHz}$ | | 270 | | MHz |
| C_{CBO} | Collector-Base Capacitance | $I_E = 0$ $V_{CB} = 10\text{ V}$ $f = 1\text{ MHz}$ | | 4 | 8 | pF |
| C_{EBO} | Emitter-Base Capacitance | $I_C = 0$ $V_{EB} = 0.5\text{ V}$ $f = 1\text{MHz}$ | | 20 | 25 | pF |
| NF | Noise Figure | $I_C = 0.1\text{ mA}$ $V_{CE} = 10\text{ V}$ $f = 1\text{ KHz}$ $\Delta f = 200\text{ Hz}$ $R_G = 1\text{ K}\Omega$ | | 4 | | dB |
| h_{ie}^* | Input Impedance | $V_{CE} = 10\text{ V}$ $I_C = 1\text{ mA}$ $f = 1\text{ KHz}$ $V_{CE} = 10\text{ V}$ $I_C = 10\text{ mA}$ $f = 1\text{ KHz}$ | 2 0.25 | | 8 1.25 | $\text{K}\Omega$ $\text{K}\Omega$ |
| h_{re}^* | Reverse Voltage Ratio | $V_{CE} = 10\text{ V}$ $I_C = 1\text{ mA}$ $f = 1\text{ KHz}$ $V_{CE} = 10\text{ V}$ $I_C = 10\text{ mA}$ $f = 1\text{ KHz}$ | | | 8 4 | 10^{-4} 10^{-4} |
| h_{fe}^* | Small Signal Current Gain | $V_{CE} = 10\text{ V}$ $I_C = 1\text{ mA}$ $f = 1\text{ KHz}$ $V_{CE} = 10\text{ V}$ $I_C = 10\text{ mA}$ $f = 1\text{ KHz}$ | 50 75 | | 300 375 | |
| h_{oe}^* | Output Admittance | $V_{CE} = 10\text{ V}$ $I_C = 1\text{ mA}$ $f = 1\text{ KHz}$ $V_{CE} = 10\text{ V}$ $I_C = 10\text{ mA}$ $f = 1\text{ KHz}$ | 5 25 | | 35 200 | μS μS |

* Pulsed: Pulse duration = 300 μs , duty cycle $\leq 2\%$

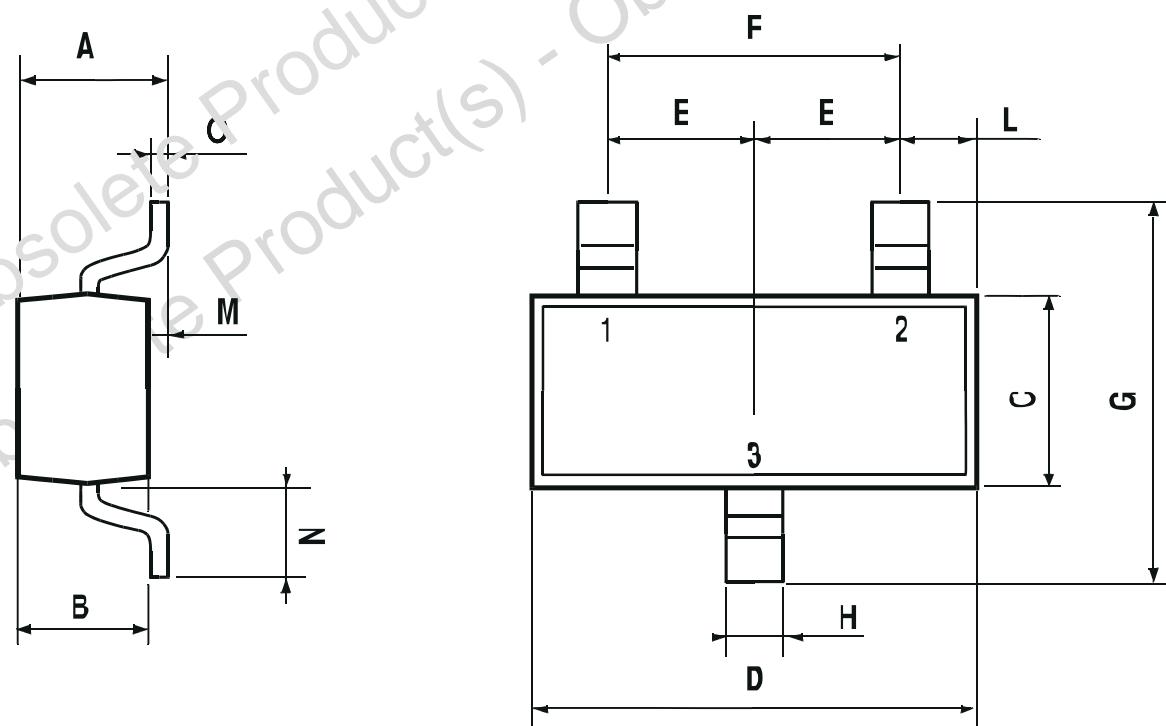
ELECTRICAL CHARACTERISTICS (Continued)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|---------------|------------------|--|-------------|-------------|-------------|-------------|
| t_d | Delay Time | $I_C = 150 \text{ mA}$ $I_B = 15 \text{ mA}$ $V_{CC} = 30 \text{ V}$ | | 5 | 10 | ns |
| t_r | Rise Time | | | 12 | 25 | ns |
| t_s | Storage Time | $I_C = 150 \text{ mA}$ $I_{B1} = -I_{B2} = 15 \text{ mA}$ $V_{CC} = 30 \text{ V}$ | | 185 | 225 | ns |
| t_f | Fall Time | | | 24 | 60 | ns |

* Pulsed: Pulse duration = 300 μs , duty cycle $\leq 2 \%$

| SOT-23 MECHANICAL DATA | | | | | | |
|------------------------|------|------|------|-------|------|------|
| DIM. | mm | | | mils | | |
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 0.85 | | 1.1 | 33.4 | | 43.3 |
| B | 0.65 | | 0.95 | 25.6 | | 37.4 |
| C | 1.20 | | 1.4 | 47.2 | | 55.1 |
| D | 2.80 | | 3 | 110.2 | | 119 |
| E | 0.95 | | 1.05 | 37.4 | | 41.3 |
| F | 1.9 | | 2.05 | 74.8 | | 80.7 |
| G | 2.1 | | 2.5 | 82.6 | | 98.4 |
| H | 0.38 | | 0.48 | 14.9 | | 18.8 |
| L | 0.3 | | 0.6 | 11.8 | | 23.6 |
| M | 0 | | 0.1 | 0 | | 3.9 |
| N | 0.3 | | 0.65 | 11.8 | | 25.6 |
| O | 0.09 | | 0.17 | 3.5 | | 6.7 |

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|------|------|------|------|-------|------|------|
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